### **Vishay Semiconductors**

www.vishay.com

# Hyperfast Rectifier, 30 A FRED Pt®



#### LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub>	30 A					
V <sub>R</sub>	600 V					
V <sub>F</sub> at I <sub>F</sub>	1.40 V					
t <sub>rr</sub> (typ.)	22 ns					
T <sub>J</sub> max.	175 °C					
Package	TO-220 FullPAK 2L					
Circuit configuration	Single					

#### FEATURES

- Hyperfast soft recovery time
- Low forward voltage drop
- 175 °C operating junction temperature
- Low leakage current
- Fully isolated package (V<sub>INS</sub> = 2500 V<sub>RMS</sub>)
- True 2 pin package
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### **DESCRIPTION / APPLICATIONS**

Hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of switch mode power supplies and inverters (air conditioning, high-frequency welding, UPS, and motor drives)

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

#### **MECHANICAL DATA**

Case: TO-220 FullPACK 2L

Molding compound meets UL 94 V-0 flammability rating

Terminals: matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Peak repetitive reverse voltage	V <sub>RRM</sub>		600	V				
Average rectified forward current in DC	I <sub>F(AV)</sub>		30	^				
Non-repetitive peak surge current	I <sub>FSM</sub>	T <sub>J</sub> = 25 °C	280	A				
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C				

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 $^{\circ}$ C unless otherwise specified)								
PARAMETER	SYMBOL	TYP.	MAX.	UNITS				
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA	600	-	-			
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 30 A	-	1.70	2.15	V		
		I <sub>F</sub> = 30 A, T <sub>J</sub> = 150 °C	-	1.40	1.65			
Reverse leakage current	I <sub>R</sub>	$V_{\rm R} = V_{\rm R}$ rated	-	0.02	10			
		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$ - 36			300	μA		
Junction capacitance	CT	V <sub>R</sub> = 600 V	-	19	-	pF		

Revision: 28-Feb-2023

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Document Number: 96786

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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25$ °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS			
		$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 100$	-	22	-				
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	90	-	ns A nC		
		T <sub>J</sub> = 125 °C		-	110	-			
De als vers a survey at	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C	l <sub>F</sub> = 30 A, dl <sub>F</sub> /dt = 200 A/μs,	-	4.1	-			
Peak recovery current		T <sub>J</sub> = 125 °C	$V_{\rm B} = 400 \text{ V}$	-	9.4	-			
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	230	-			
		T <sub>J</sub> = 125 °C		-	730	-			

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55	-	175	°C		
Thermal resistance, junction-to-case	R <sub>thJC</sub>		-	2.40	3.10			
Thermal resistance, junction-to-ambient	R <sub>thJA</sub>	Typical socket mount	-	45	-	°C/W		
Typical thermal resistance, case-to-heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth, and greased	-	0.5	-			
Weight			-	2	-	g		
Weight			-	0.07	-	oz.		
Mounting torque			6 (5)	-	12 (10)	kgf · cm (lbf · in)		
Marking device		Case style TO-220 FullPAK 2L		ETH3 <sup>-</sup>	106FP			



VS-ETH3106FP-N3

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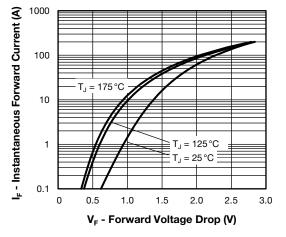


Fig. 1 - Forward Voltage Drop Characteristics

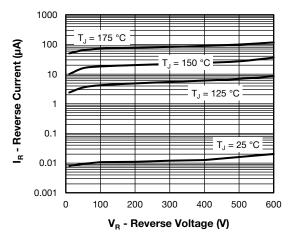


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

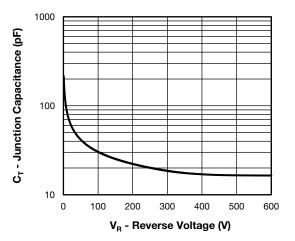


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

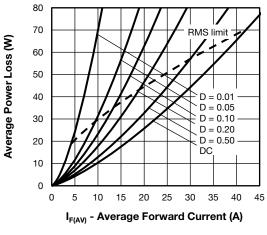
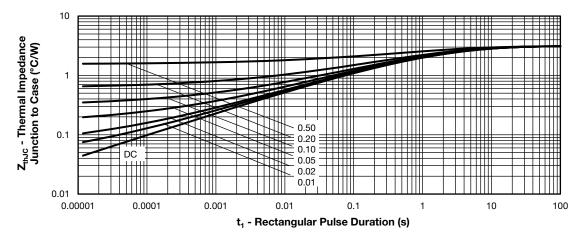
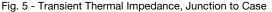


Fig. 4 - Forward Power Loss Characteristics





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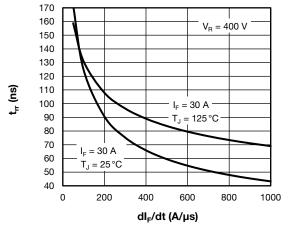


Fig. 6 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

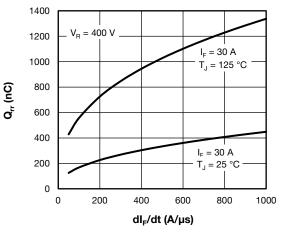


Fig. 7 - Typical Reverse Recovery Charge vs. dl<sub>F</sub>/dt

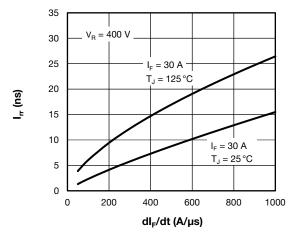


Fig. 8 - Typical Reverse Recovery Current vs. dl<sub>F</sub>/dt





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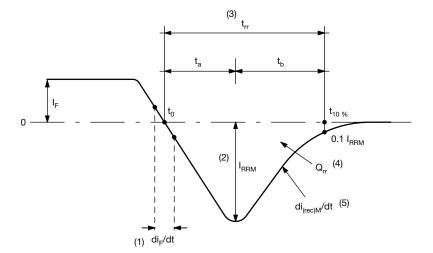


Fig. 9 - Reverse Recovery Waveform and Definitions

- Notes
- <sup>(1)</sup> di<sub>F</sub>/dt rate of change of current through zero crossing
- <sup>(2)</sup> I<sub>RRM</sub> peak reverse recovery current
- $^{(3)}$  t<sub>rr</sub> reverse recovery time measured from t<sub>0</sub>, crossing point of negative going I<sub>F</sub>, to point t<sub>10%</sub>, 0.1 I<sub>RRM</sub>
- <sup>(4)</sup>  $Q_{rr}$  area under curve defined by  $t_0$  and  $t_{10\%}$

$$Q_{rr} = \int_{t_0}^{t_{10}\%} I(t)dt$$

<sup>(5)</sup> di<sub>(rec)</sub>M/dt - peak rate of change of current during t<sub>b</sub> portion of t<sub>rr</sub>

#### **ORDERING INFORMATION TABLE**

Devi

ice code	VS-	Е	т	н	31	06	FP	-N3
	(1)	(2)	(3)	(4)	(5)	(6)	(7)	(8)
	1 - 2 -	Circ	5	niconduo		oduct		C
	3 - 4 - 5 -	T = H =	TO-220 hyperfa	) ast recov de: 31 =	5	е		
	6 - 7 - 8 -	Volt	age coo = TO-22	de: 06 = 0 FullP/ ntal digit	600 V AK 2L			
				gen-free		-compli	ant, and	d totally

LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?96157					
Part marking information	www.vishay.com/doc?95392				

Revision: 28-Feb-2023

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